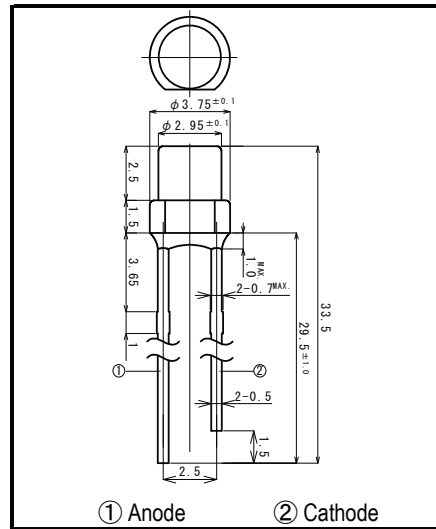


# R-660-380C3

# Visible Light Emitting Diode



- FEATURES**
- High-output Power
  - Compact
  - Wide Viewing Angle
  - High Reliability
- APPLICATIONS**
- Optical Switches
  - Optical Sensors

## 1. ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

ITEM	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	50	mA
Forward Current (Pulse)*1	IFP	0.5	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	110	mW
Operating Temp.	Topr	-20 TO 80	°C
Storage Temp.	Tstg	-30 TO 100	°C
Junction Temp.	Tj	100	°C
Lead Soldering Temp.*2	Tls	260	°C

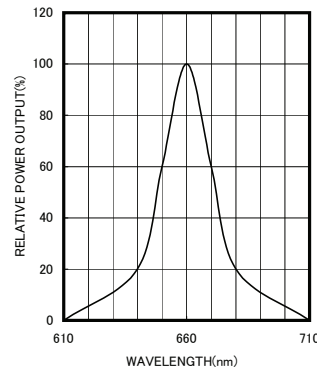
\*1: Tw=10 μs, T=10 ms

\*2: Time 5 Sec max, Position: Up to 3 mm from the body

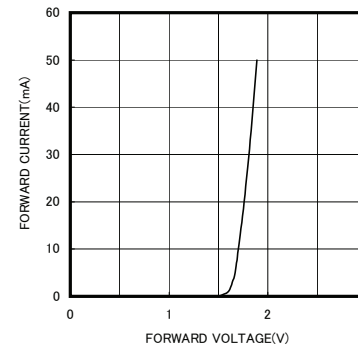
## 2. ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25°C)

ITEM	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=20 mA	2.5	4.0		mW
Forward Voltage	VF	IF=20 mA		1.8	2.2	V
Reverse Current	IR	VR=5 V			100	μA
Peak Wavelength	λp	IF=20 mA		660		nm
Spectral Line Half Width	Δλ	IF=20 mA		25		nm
Half Intensity Beam Angle	θ	IF=20 mA		±40		deg.
Rise Time	Tr	IFP=20 mA		30		nS
Fall Time	Tf	IFP=20 mA		30		nS
Junction Capacitance	Cj	1 MHz, V=0 V		20		pF

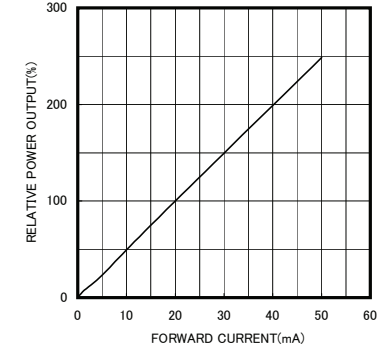
SPECTRAL OUTPUT



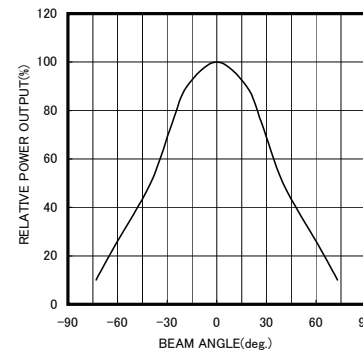
FORWARD I-V CHARACTERISTICS



RELATIVE POWER vs FORWARD CURRENT



RADIATION PATTERN



THERMAL DERATING CURVE

